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#### Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

#### Applications of **Embedded - Microprocessors**

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

#### Details

E·XF

Product Status	Active
Core Processor	PowerPC e300c2
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	266MHz
Co-Processors/DSP	Communications; QUICC Engine, Security; SEC 2.2
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100Mbps (3)
SATA	-
USB	USB 2.0 (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	0°C ~ 105°C (TA)
Security Features	Cryptography
Package / Case	516-BBGA
Supplier Device Package	516-FPBGA (27x27)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mpc8323ezqaddc

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

## NOTE

The QUICC Engine block can also support a UTOPIA level 2 capable of supporting 31 multi-PHY (MPC8323E- and MPC8323-specific).

The MPC8323E security engine (SEC 2.2) allows CPU-intensive cryptographic operations to be offloaded from the main CPU core. The security-processing accelerator provides hardware acceleration for the DES, 3DES, AES, SHA-1, and MD-5 algorithms.

In summary, the MPC8323E family provides users with a highly integrated, fully programmable communications processor. This helps ensure that a low-cost system solution can be quickly developed and offers flexibility to accommodate new standards and evolving system requirements.

# 1.1 MPC8323E Features

Major features of the MPC8323E are as follows:

- High-performance, low-power, and cost-effective single-chip data-plane/control-plane solution for ATM or IP/Ethernet packet processing (or both).
- MPC8323E QUICC Engine block offers a future-proof solution for next generation designs by supporting programmable protocol termination and network interface termination to meet evolving protocol standards.
- Single platform architecture supports the convergence of IP packet networks and ATM networks.
- DDR1/DDR2 memory controller—one 32-bit interface at up to 266 MHz supporting both DDR1 and DDR2.
- An e300c2 core built on Power Architecture technology with 16-Kbyte instruction and data caches, and dual integer units.
- Peripheral interfaces such as 32-bit PCI (2.2) interface up to 66-MHz operation, 16-bit local bus interface up to 66-MHz operation, and USB 2.0 (full-/low-speed).
- Security engine provides acceleration for control and data plane security protocols.
- High degree of software compatibility with previous-generation PowerQUICC processor-based designs for backward compatibility and easier software migration.

# 1.1.1 Protocols

The protocols are as follows:

- ATM SAR up to 155 Mbps (OC-3) full duplex, with ATM traffic shaping (ATF TM4.1)
- Support for ATM AAL1 structured and unstructured circuit emulation service (CES 2.0)
- Support for IMA and ATM transmission convergence sub-layer
- ATM OAM handling features compatible with ITU-T I.610
- IP termination support for IPv4 and IPv6 packets including TOS, TTL, and header checksum processing
- Extensive support for ATM statistics and Ethernet RMON/MIB statistics
- Support for 64 channels of HDLC/transparent



# 1.1.2 Serial Interfaces

The MPC8323E serial interfaces are as follows:

- Support for one UL2 interface with 31 multi-PHY addresses (MPC8323E and MPC8323 only)
- Support for up to three 10/100 Mbps Ethernet interfaces using MII or RMII
- Support for up to four T1/E1/J1/E3 or DS-3 serial interfaces (TDM)
- Support for dual UART and SPI interfaces and a single I<sup>2</sup>C interface

# 1.2 QUICC Engine Block

The QUICC Engine block is a versatile communications complex that integrates several communications peripheral controllers. It provides on-chip system design for a variety of applications, particularly in communications and networking systems. The QUICC Engine block has the following features:

- One 32-bit RISC controller for flexible support of the communications peripherals
- Serial DMA channel for receive and transmit on all serial channels
- Five universal communication controllers (UCCs) supporting the following protocols and interfaces (not all of them simultaneously):
  - 10/100 Mbps Ethernet/IEEE 802.3® standard
  - IP support for IPv4 and IPv6 packets including TOS, TTL, and header checksum processing
  - ATM protocol through UTOPIA interface (note that the MPC8321 and MPC8321E do not support the UTOPIA interface)
  - HDLC /transparent up to 70-Mbps full-duplex
  - HDLC bus up to 10 Mbps
  - Asynchronous HDLC
  - UART
  - BISYNC up to 2 Mbps
  - QUICC multi-channel controller (QMC) for 64 TDM channels
- One UTOPIA interface (UPC1) supporting 31 multi-PHYs (MPC8323E- and MPC8323-specific)
- Two serial peripheral interfaces (SPI). SPI2 is dedicated to Ethernet PHY management.
- Four TDM interfaces
- Thirteen independent baud rate generators and 19 input clock pins for supplying clocks to UCC serial channels
- Four independent 16-bit timers that can be interconnected as two 32-bit timers

The UCCs are similar to the PowerQUICC II peripherals: SCC (BISYNC, UART, and HDLC bus) and FCC (fast Ethernet, HDLC, transparent, and ATM).





# 1.3 Security Engine

The security engine is optimized to handle all the algorithms associated with IPSec, IEEE 802.11i<sup>TM</sup> standard, and iSCSI. The security engine contains one crypto-channel, a controller, and a set of crypto execution units (EUs). The execution units are:

- Data encryption standard execution unit (DEU), supporting DES and 3DES
- Advanced encryption standard unit (AESU), supporting AES
- Message digest execution unit (MDEU), supporting MD5, SHA1, SHA-256, and HMAC with any algorithm
- One crypto-channel supporting multi-command descriptor chains

# 1.4 DDR Memory Controller

The MPC8323E DDR1/DDR2 memory controller includes the following features:

- Single 32-bit interface supporting both DDR1 and DDR2 SDRAM
- Support for up to 266-MHz data rate
- Support for two ×16 devices
- Support for up to 16 simultaneous open pages
- Supports auto refresh
- On-the-fly power management using CKE
- 1.8-/2.5-V SSTL2 compatible I/O
- Support for 1 chip select only
- FCRAM, ECC, hardware/software calibration, bit deskew, QIN stage, or atomic logic are not supported.

# 1.5 PCI Controller

The MPC8323E PCI controller includes the following features:

- PCI Specification Revision 2.3 compatible
- Single 32-bit data PCI interface operates up to 66 MHz
- PCI 3.3-V compatible (not 5-V compatible)
- Support for host and agent modes
- On-chip arbitration, supporting three external masters on PCI
- Selectable hardware-enforced coherency

# **1.6 Programmable Interrupt Controller (PIC)**

The programmable interrupt controller (PIC) implements the necessary functions to provide a flexible solution for general-purpose interrupt control. The PIC programming model is compatible with the MPC8260 interrupt controller, and it supports 8 external and 35 internal discrete interrupt sources. Interrupts can also be redirected to an external interrupt controller.



**Clock Input Timing** 

Local bus I/O load = 25 pF 1 pair of clocks	66 MHz, 32 bits	_		0.12	W	_
PCI I/O load = 30 pF	66 MHz, 32 bits	—		0.057	W	_
QUICC Engine block and	UTOPIA 8-bit 31 PHYs	—	_	0.041	W	Multiply by
other I/Os	TDM serial	—	_	0.001	W	interfaces used.
	TDM nibble	—	_	0.004	W	
	HDLC/TRAN serial	—	_	0.003	W	
	HDLC/TRAN nibble	—	_	0.025	W	
	DUART	—	_	0.017	W	
	Mils	—	_	0.009	W	
	RMII	—	_	0.009	W	
	Ethernet management	—	_	0.002	W	
	USB	—	_	0.001	W	
	SPI	—	—	0.001	W	
	Timer output	—	—	0.002	W	

Table 6. Estimated Typical I/O Power Dissipation (continued)

## NOTE

 $AV_{DD}n$  (1.0 V) is estimated to consume 0.05 W (under normal operating conditions and ambient temperature).

# 4 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8323E.

## NOTE

The rise/fall time on QUICC Engine input pins should not exceed 5 ns. This should be enforced especially on clock signals. Rise time refers to signal transitions from 10% to 90% of VCC; fall time refers to transitions from 90% to 10% of VCC.

# 4.1 DC Electrical Characteristics

Table 7 provides the clock input (CLKIN/PCI\_SYNC\_IN) DC timing specifications for the MPC8323E.

Parameter	Condition	Symbol	Min	Мах	Unit
Input high voltage	—	V <sub>IH</sub>	2.7	OV <sub>DD</sub> + 0.3	V
Input low voltage	_	V <sub>IL</sub>	-0.3	0.4	V

## Table 7. CLKIN DC Electrical Characteristics



CLKIN input current	$0 \ V \leq V_{IN} \leq OV_{DD}$	I <sub>IN</sub>	_	±5	μA
PCI_SYNC_IN input current	$\begin{array}{c} 0 \ V \leq V_{IN} \leq 0.5 \ V \ or \\ OV_{DD} - 0.5 \ V \leq V_{IN} \leq OV_{DD} \end{array}$	I <sub>IN</sub>	_	±5	μA
PCI_SYNC_IN input current	$0.5~V \leq V_{IN} \leq OV_{DD} - 0.5~V$	I <sub>IN</sub>	—	±50	μA

# 4.2 AC Electrical Characteristics

The primary clock source for the MPC8323E can be one of two inputs, CLKIN or PCI\_CLK, depending on whether the device is configured in PCI host or PCI agent mode. Table 8 provides the clock input (CLKIN/PCI\_CLK) AC timing specifications for the MPC8323E.

Parameter/Condition	Symbol	Min	Typical	Мах	Unit	Notes
CLKIN/PCI_CLK frequency	f <sub>CLKIN</sub>	25	—	66.67	MHz	1
CLKIN/PCI_CLK cycle time	t <sub>CLKIN</sub>	15	—	—	ns	—
CLKIN rise and fall time	t <sub>KH</sub> , t <sub>KL</sub>	0.6	0.8	4	ns	2
PCI_CLK rise and fall time	t <sub>PCH</sub> , t <sub>PCL</sub>	0.6	0.8	1.2	ns	2
CLKIN/PCI_CLK duty cycle	t <sub>KHK</sub> /t <sub>CLKIN</sub>	40	—	60	%	3
CLKIN/PCI_CLK jitter		—	—	±150	ps	4, 5

**Table 8. CLKIN AC Timing Specifications** 

Notes:

1. **Caution:** The system, core, security, and QUICC Engine block must not exceed their respective maximum or minimum operating frequencies.

2. Rise and fall times for CLKIN/PCI\_CLK are measured at 0.4 and 2.7 V.

3. Timing is guaranteed by design and characterization.

4. This represents the total input jitter—short term and long term—and is guaranteed by design.

5. The CLKIN/PCI\_CLK driver's closed loop jitter bandwidth should be < 500 kHz at -20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track CLKIN drivers with the specified jitter.

# 5 **RESET Initialization**

This section describes the AC electrical specifications for the reset initialization timing requirements of the MPC8323E. Table 9 provides the reset initialization AC timing specifications for the reset component(s).

Table 9. RESET Initialization Timir	g Specifications
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Parameter/Condition	Min	Max	Unit	Notes
Required assertion time of $\overrightarrow{\text{HRESET}}$ or $\overrightarrow{\text{SRESET}}$ (input) to activate reset flow	32	_	t <sub>PCI_SYNC_IN</sub>	1
Required assertion time of $\overrightarrow{\text{PORESET}}$ with stable clock applied to CLKIN when the MPC8323E is in PCI host mode	32		t <sub>CLKIN</sub>	2
Required assertion time of PORESET with stable clock applied to PCI_SYNC_IN when the MPC8323E is in PCI agent mode	32	_	<sup>t</sup> PCI_SYNC_IN	1



Parameter/Condition	Min	Max	Unit	Notes
HRESET/SRESET assertion (output)	512	_	t <sub>PCI_SYNC_IN</sub>	1
HRESET negation to SRESET negation (output)	16		t <sub>PCI_SYNC_IN</sub>	1
Input setup time for POR configuration signals (CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV) with respect to negation of PORESET when the MPC8323E is in PCI host mode	4	_	<sup>t</sup> CLKIN	2
Input setup time for POR configuration signals (CFG_RESET_SOURCE[0:2] and CFG_CLKIN_DIV) with respect to negation of PORESET when the MPC8323E is in PCI agent mode	4	_	<sup>t</sup> PCI_SYNC_IN	1
Input hold time for POR config signals with respect to negation of HRESET	0	_	ns	—
Time for the MPC8323E to turn off POR configuration signals with respect to the assertion of $\overrightarrow{\text{HRESET}}$	_	4	ns	3
Time for the MPC8323E to turn on POR configuration signals with respect to the negation of HRESET	1	_	<sup>t</sup> PCI_SYNC_IN	1, 3

### Table 9. RESET Initialization Timing Specifications (continued)

## Notes:

1. t<sub>PCI\_SYNC\_IN</sub> is the clock period of the input clock applied to PCI\_SYNC\_IN. When the MPC8323E is In PCI host mode the primary clock is applied to the CLKIN input, and PCI\_SYNC\_IN period depends on the value of CFG\_CLKIN\_DIV. See the *MPC8323E PowerQUICC II Pro Integrated Communications Processor Reference Manual* for more details.

 t<sub>CLKIN</sub> is the clock period of the input clock applied to CLKIN. It is only valid when the MPC8323E is in PCI host mode. See the MPC8323E PowerQUICC II Pro Integrated Communications Processor Reference Manual for more details.

3. POR configuration signals consists of CFG\_RESET\_SOURCE[0:2] and CFG\_CLKIN\_DIV.

## Table 10 provides the PLL lock times.

## Table 10. PLL Lock Times

Parameter/Condition	Min	Мах	Unit	Notes
PLL lock times		100	μs	_

# 5.1 Reset Signals DC Electrical Characteristics

Table 11 provides the DC electrical characteristics for the MPC8323E reset signals mentioned in Table 9.

Table 11. Reset Signals DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Мах	Unit	Notes
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -6.0 mA	2.4	—	V	1
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 6.0 mA	—	0.5	V	1
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3.2 mA	—	0.4	V	1
Input high voltage	V <sub>IH</sub>	—	2.0	OV <sub>DD</sub> + 0.3	V	1
Input low voltage	V <sub>IL</sub>	_	-0.3	0.8	V	_



#### DDR1 and DDR2 SDRAM

Figure 5 shows the DDR SDRAM output timing for the MCK to MDQS skew measurement (t<sub>DDKHMH</sub>).



Figure 5. Timing Diagram for t<sub>DDKHMH</sub>

Figure 6 shows the DDR1 and DDR2 SDRAM output timing diagram.



Figure 6. DDR1 and DDR2 SDRAM Output Timing Diagram



#### **Ethernet and MII Management**

Table 26. RMII Receive AC Timing Specifications (continued)

At recommended operating conditions with  $\text{OV}_{\text{DD}}$  of 3.3 V  $\pm$  10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Typical	Max	Unit
REF_CLK clock fall time $V_{IH}(max)$ to $V_{IL}(min)$	t <sub>RMXF</sub>	1.0		4.0	ns

#### Note:

1. The symbols used for timing specifications follow the pattern of t<sub>(first three letters of functional block)(signal)(state)(reference)(state)(signal)(state) for outputs. For example, t<sub>RMRDVKH</sub> symbolizes RMII receive timing (RMR) with respect to the time data input signals (D) reach the valid state (V) relative to the t<sub>RMX</sub> clock reference (K) going to the high (H) state or setup time. Also, t<sub>RMRDXKL</sub> symbolizes RMII receive timing (RMR) with respect to the tinvalid (X) relative to the t<sub>RMX</sub> clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t<sub>RMX</sub> represents the RMII (RM) reference (X) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).</sub>

## Figure 11 provides the AC test load.



Figure 11. AC Test Load

Figure 12 shows the RMII receive AC timing diagram.



Figure 12. RMII Receive AC Timing Diagram

# 8.3 Ethernet Management Interface Electrical Characteristics

The electrical characteristics specified here apply to MII management interface signals MDIO (management data input/output) and MDC (management data clock). The electrical characteristics for MII, and RMII are specified in Section 8.1, "Ethernet Controller (10/100 Mbps)—MII/RMII Electrical Characteristics."



# 8.3.1 MII Management DC Electrical Characteristics

MDC and MDIO are defined to operate at a supply voltage of 3.3 V. The DC electrical characteristics for MDIO and MDC are provided in Table 27.

Parameter	Symbol	Conditions		Min	Max	Unit
Supply voltage (3.3 V)	OV <sub>DD</sub>	—		2.97	3.63	V
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -1.0 mA	OV <sub>DD</sub> = Min	2.10	OV <sub>DD</sub> + 0.3	V
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 1.0 mA	OV <sub>DD</sub> = Min	GND	0.50	V
Input high voltage	V <sub>IH</sub>	-	_		—	V
Input low voltage	V <sub>IL</sub>	—		—	0.80	V
Input current	I <sub>IN</sub>	$0 V \le V_{IN} \le OV_{DD}$		—	±5	μA

Table 27. MII Management DC Electrical Characteristics When Powered at 3.3 V

# 8.3.2 MII Management AC Electrical Specifications

Table 28 provides the MII management AC timing specifications.

#### Table 28. MII Management AC Timing Specifications

At recommended operating conditions with  $\text{OV}_{\text{DD}}$  is 3.3 V  $\pm$  10%.

Parameter/Condition	Symbol <sup>1</sup>	Min	Typical	Мах	Unit	Notes
MDC frequency	f <sub>MDC</sub>	—	2.5	—	MHz	_
MDC period	t <sub>MDC</sub>	—	400	—	ns	_
MDC clock pulse width high	t <sub>MDCH</sub>	32	—	—	ns	_
MDC to MDIO delay	t <sub>MDKHDX</sub>	10	—	70	ns	_
MDIO to MDC setup time	t <sub>MDDVKH</sub>	5	—	—	ns	_
MDIO to MDC hold time	t <sub>MDDXKH</sub>	0	—	—	ns	_
MDC rise time	t <sub>MDCR</sub>	—	—	10	ns	_
MDC fall time	t <sub>MDHF</sub>	—	—	10	ns	

Note:

The symbols used for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>MDKHDX</sub> symbolizes management data timing (MD) for the time t<sub>MDC</sub> from clock reference (K) high (H) until data outputs (D) are invalid (X) or data hold time. Also, t<sub>MDDVKH</sub> symbolizes management data timing (MD) with respect to the time data input signals (D) reach the valid state (V) relative to the t<sub>MDC</sub> clock reference (K) going to the high (H) state or setup time. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).
</sub>



Figure 17. Local Bus Signals, GPCM/UPM Signals for LCRR[CLKDIV] = 4

# 10 JTAG

This section describes the DC and AC electrical specifications for the IEEE Std. 1149.1<sup>TM</sup> (JTAG) interface of the MPC8323E.

# **10.1 JTAG DC Electrical Characteristics**

Table 31 provides the DC electrical characteristics for the IEEE Std. 1149.1 (JTAG) interface of the MPC8323E.

Table 31. JTAG	Interface D	OC Electrical	Characteristics
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Characteristic	Symbol	Condition	Min	Мах	Unit
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -6.0 mA	2.4	—	V
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 6.0 mA	_	0.5	V
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3.2 mA	_	0.4	V
Input high voltage	V <sub>IH</sub>	—	2.5	OV <sub>DD</sub> + 0.3	V



JTAG

Table 31. JTAG Interface DC Electrical Characteristics (	continued)
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Characteristic	Symbol	Condition	Min	Мах	Unit
Input low voltage	V <sub>IL</sub>	—	-0.3	0.8	V
Input current	I <sub>IN</sub>	$0~V \leq V_{IN} \leq OV_{DD}$	—	±5	μA

# **10.2 JTAG AC Electrical Characteristics**

This section describes the AC electrical specifications for the IEEE Std. 1149.1 (JTAG) interface of the MPC8323E. Table 32 provides the JTAG AC timing specifications as defined in Figure 19 through Figure 22.

## Table 32. JTAG AC Timing Specifications (Independent of CLKIN)<sup>1</sup>

At recommended operating conditions (see Table 2).

Parameter	Symbol <sup>2</sup>	Min	Мах	Unit	Notes
JTAG external clock frequency of operation	f <sub>JTG</sub>	0	33.3	MHz	
JTAG external clock cycle time	t <sub>JTG</sub>	30	_	ns	_
JTAG external clock pulse width measured at 1.4 V	t <sub>JTKHKL</sub>	11	—	ns	—
JTAG external clock rise and fall times	t <sub>JTGR</sub> , t <sub>JTGF</sub>	0	2	ns	—
TRST assert time	t <sub>TRST</sub>	25	—	ns	3
Input setup times: Boundary-scan data TMS, TDI	t <sub>JTDVKH</sub> t <sub>JTIVKH</sub>	4 4		ns	4
Input hold times: Boundary-scan data TMS, TDI	<sup>t</sup> jtdxkh t <sub>jtixkh</sub>	10 10		ns	4
Valid times: Boundary-scan data TDO	tjtkldv tjtklov	2 2	15 15	ns	5
Output hold times: Boundary-scan data TDO	t <sub>jtkldx</sub> t <sub>jtklox</sub>	2 2	_	ns	5



# 11 I<sup>2</sup>C

This section describes the DC and AC electrical characteristics for the I<sup>2</sup>C interface of the MPC8323E.

# 11.1 I<sup>2</sup>C DC Electrical Characteristics

Table 33 provides the DC electrical characteristics for the I<sup>2</sup>C interface of the MPC8323E.

## Table 33. I<sup>2</sup>C DC Electrical Characteristics

At recommended operating conditions with  $\text{OV}_{\text{DD}}$  of 3.3 V  $\pm$  10%.

Parameter	Symbol	Min	Мах	Unit	Notes
Input high voltage level	V <sub>IH</sub>	$0.7  imes OV_{DD}$	OV <sub>DD</sub> + 0.3	V	
Input low voltage level	V <sub>IL</sub>	-0.3	$0.3\times\text{OV}_{\text{DD}}$	V	_
Low level output voltage	V <sub>OL</sub>	0	0.4	V	1
Output fall time from $V_{IH}(min)$ to $V_{IL}(max)$ with a bus capacitance from 10 to 400 pF	<sup>t</sup> I2KLKV	$20 + 0.1 \times C_B$	250	ns	2
Pulse width of spikes which must be suppressed by the input filter	t <sub>I2KHKL</sub>	0	50	ns	3
Capacitance for each I/O pin	Cl	_	10	pF	_
Input current (0 V $\leq$ V <sub>IN</sub> $\leq$ OV <sub>DD</sub> )	I <sub>IN</sub>	—	±5	μA	4

Notes:

1. Output voltage (open drain or open collector) condition = 3 mA sink current.

2.  $C_B$  = capacitance of one bus line in pF.

3. Refer to the MPC8323E PowerQUICC II Pro Integrated Communications Processor Reference Manual for information on the digital filter used.

4. I/O pins obstructs the SDA and SCL lines if  $\ensuremath{\mathsf{OV}_{\mathsf{DD}}}$  is switched off.

# 11.2 I<sup>2</sup>C AC Electrical Specifications

Table 34 provides the AC timing parameters for the  $I^2C$  interface of the MPC8323E.

## Table 34. I<sup>2</sup>C AC Electrical Specifications

All values refer to  $V_{IH}$  (min) and  $V_{IL}$  (max) levels (see Table 33).

Parameter		Min	Мах	Unit
SCL clock frequency		0	400	kHz
Low period of the SCL clock		1.3	—	μs
High period of the SCL clock		0.6	—	μs
Setup time for a repeated START condition		0.6	—	μs
Hold time (repeated) START condition (after this period, the first clock pulse is generated)		0.6	_	μs
Data setup time		100	—	ns
Data hold time: CBUS compatible masters I <sup>2</sup> C bus devices	t <sub>I2DXKL</sub>	$\overline{0^2}$	 0.9 <sup>3</sup>	μs



PCI

## Table 37 shows the PCI AC timing specifications at 33 MHz.

	Table 37.	PCI AC	Timing	Specifications	at 33 MHz
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Parameter	Symbol <sup>1</sup>	Min	Max	Unit	Notes
Clock to output valid	<sup>t</sup> PCKHOV		11	ns	2
Output hold from clock	t <sub>PCKHOX</sub>	2	—	ns	2
Clock to output high impedence	t <sub>PCKHOZ</sub>		14	ns	2, 3
Input setup to clock	t <sub>PCIVKH</sub>	3.0	_	ns	2, 4
Input hold from clock	t <sub>PCIXKH</sub>	0	—	ns	2, 4

Notes:

The symbols used for timing specifications follow the pattern of t<sub>(first two letters of functional block)(signal)(state)(reference)(state) for inputs and t<sub>(first two letters of functional block)(reference)(state)(signal)(state)</sub> for outputs. For example, t<sub>PCIVKH</sub> symbolizes PCI timing (PC) with respect to the time the input signals (I) reach the valid state (V) relative to the PCI\_SYNC\_IN clock, t<sub>SYS</sub>, reference (K) going to the high (H) state or setup time. Also, t<sub>PCRHFV</sub> symbolizes PCI timing (PC) with respect to the time hard reset (R) went high (H) relative to the frame signal (F) going to the valid (V) state.
</sub>

- 2. See the timing measurement conditions in the PCI 2.3 Local Bus Specifications.
- 3. For purposes of active/float timing measurements, the Hi-Z or off state is defined to be when the total current delivered through the component pin is less than or equal to the leakage current specification.
- 4. Input timings are measured at the pin.

Figure 25 provides the AC test load for PCI.



Figure 25. PCI AC Test Load

Figure 26 shows the PCI input AC timing conditions.



Figure 26. PCI Input AC Timing Measurement Conditions



Figure 28 provides the AC test load for the timers.



# 14 GPIO

This section describes the DC and AC electrical specifications for the GPIO of the MPC8323E.

# 14.1 GPIO DC Electrical Characteristics

Table 11 provides the DC electrical characteristics for the MPC8323E GPIO.

Characteristic	Symbol	Condition	Min	Мах	Unit	Notes
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -6.0 mA	2.4	—	V	1
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 6.0 mA	—	0.5	V	1
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3.2 mA	_	0.4	V	1
Input high voltage	V <sub>IH</sub>	—	2.0	OV <sub>DD</sub> + 0.3	V	1
Input low voltage	V <sub>IL</sub>	—	-0.3	0.8	V	—
Input current	I <sub>IN</sub>	$0 \ V \leq V_{IN} \leq OV_{DD}$	_	±5	μA	—

## Table 40. GPIO DC Electrical Characteristics

### Note:

1. This specification applies when operating from 3.3-V supply.

# 14.2 GPIO AC Timing Specifications

Table 41 provides the GPIO input and output AC timing specifications.

## Table 41. GPIO Input AC Timing Specifications<sup>1</sup>

Characteristic	Symbol <sup>2</sup>	Min	Unit
GPIO inputs—minimum pulse width	t <sub>PIWID</sub>	20	ns

### Notes:

1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.

2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t<sub>PIWID</sub> ns to ensure proper operation.





# 19 HDLC, BISYNC, Transparent, and Synchronous UART

This section describes the DC and AC electrical specifications for the high level data link control (HDLC), BISYNC, transparent, and synchronous UART of the MPC8323E.

# 19.1 HDLC, BISYNC, Transparent, and Synchronous UART DC Electrical Characteristics

Table 50 provides the DC electrical characteristics for the MPC8323E HDLC, BISYNC, transparent, and synchronous UART protocols.

Table 50. HDLC, BISYNC, Transparent, and	Synchronous UART DC Electrical Characteristics
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Characteristic	Symbol	Condition	Min	Мах	Unit
Output high voltage	V <sub>OH</sub>	I <sub>OH</sub> = -2.0 mA	2.4	—	V
Output low voltage	V <sub>OL</sub>	I <sub>OL</sub> = 3.2 mA	_	0.5	V
Input high voltage	V <sub>IH</sub>	—	2.0	OV <sub>DD</sub> + 0.3	V
Input low voltage	V <sub>IL</sub>	—	-0.3	0.8	V
Input current	I <sub>IN</sub>	$0 V \le V_{IN} \le OV_{DD}$	—	±5	μA

# 19.2 HDLC, BISYNC, Transparent, and Synchronous UART AC Timing Specifications

Table 51 provides the input and output AC timing specifications for HDLC, BISYNC, and transparent UART protocols.

Characteristic	Symbol <sup>2</sup>	Min	Мах	Unit
Outputs—Internal clock delay	t <sub>HIKHOV</sub>	0	5.5	ns
Outputs—External clock delay	t <sub>HEKHOV</sub>	1	10	ns
Outputs—Internal clock high impedance	t <sub>нікнох</sub>	0	5.5	ns
Outputs—External clock high impedance	t <sub>HEKHOX</sub>	1	8	ns
Inputs—Internal clock input setup time	t <sub>HIIVKH</sub>	6	—	ns
Inputs—External clock input setup time	t <sub>HEIVKH</sub>	4	—	ns
Inputs—Internal clock input hold time	t <sub>нихкн</sub>	0	—	ns

Table 51. HDLC, BISYNC, and Transparent UART AC Timing Specifications<sup>1</sup>



USB

# 20 USB

This section provides the AC and DC electrical specifications for the USB interface of the MPC8323E.

# 20.1 USB DC Electrical Characteristics

Table 53 provides the DC electrical characteristics for the USB interface.

## Table 53. USB DC Electrical Characteristics<sup>1</sup>

Parameter	Symbol	Min	Мах	Unit
High-level input voltage	V <sub>IH</sub>	2	OV <sub>DD</sub> + 0.3	V
Low-level input voltage	V <sub>IL</sub>	-0.3	0.8	V
High-level output voltage, $I_{OH} = -100 \ \mu A$	V <sub>OH</sub>	OV <sub>DD</sub> – 0.2	—	V
Low-level output voltage, $I_{OL} = 100 \ \mu A$	V <sub>OL</sub>	—	0.2	V
Input current	I <sub>IN</sub>	-	±5	μA

## Note:

1. Note that the symbol  $V_{IN}$ , in this case, represents the  $OV_{IN}$  symbol referenced in Table 1 and Table 2.

# 20.2 USB AC Electrical Specifications

Table 54 describes the general timing parameters of the USB interface of the MPC8323E.

Table 54. 03D General Tilling Parameters	Table 54.	USB	General	Timing	Parameters
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Parameter	Symbol <sup>1</sup>	Min	Мах	Unit	Notes
USB clock cycle time	t <sub>USCK</sub>	20.83	—	ns	Full speed 48 MHz
USB clock cycle time	t <sub>USCK</sub>	166.67	—	ns	Low speed 6 MHz
Skew between TXP and TXN	t <sub>USTSPN</sub>	_	5	ns	—
Skew among RXP, RXN, and RXD	t <sub>USRSPND</sub>	_	10	ns	Full speed transitions
Skew among RXP, RXN, and RXD	tUSRPND		100	ns	Low speed transitions

### Notes:

 The symbols used for timing specifications follow the pattern of t<sub>(first two letters of functional block)(state)(signal)</sub> for receive signals and t<sub>(first two letters of functional block)(state)(signal)</sub> for transmit signals. For example, t<sub>USRSPND</sub> symbolizes USB timing (US) for the USB receive signals skew (RS) among RXP, RXN, and RXD (PND). Also, t<sub>USTSPN</sub> symbolizes USB timing (US) for the USB transmit signals skew (TS) between TXP and TXN (PN).

2. Skew measurements are done at  $OV_{DD}/2$  of the rising or falling edge of the signals.

Figure 41 provide the AC test load for the USB.



Figure 41. USB AC Test Load



Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPIO_PC10/UPC1_RxDATA[2]/SER5_RXD[2]	B21	IO	OV <sub>DD</sub>	—
GPIO_PC11/UPC1_RxDATA[3]/SER5_RXD[3]	A20	IO	OV <sub>DD</sub>	—
GPIO_PC12/UPC1_RxDATA[4]	D19	IO	OV <sub>DD</sub>	—
GPIO_PC13/UPC1_RxDATA[5]/LSRCID0	C18	IO	OV <sub>DD</sub>	—
GPIO_PC14/UPC1_RxDATA[6]/LSRCID1	D18	IO	OV <sub>DD</sub>	—
GPIO_PC15/UPC1_RxDATA[7]/LSRCID2	A25	IO	OV <sub>DD</sub>	—
GPIO_PC16/UPC1_TxADDR[0]	C21	IO	OV <sub>DD</sub>	—
GPIO_PC17/UPC1_TxADDR[1]/LSRCID3	D22	IO	OV <sub>DD</sub>	—
GPIO_PC18/UPC1_TxADDR[2]/LSRCID4	C23	IO	OV <sub>DD</sub>	—
GPIO_PC19/UPC1_TxADDR[3]/LDVAL	D23	IO	OV <sub>DD</sub>	—
GPIO_PC20/UPC1_RxADDR[0]	C17	IO	OV <sub>DD</sub>	—
GPIO_PC21/UPC1_RxADDR[1]	D17	IO	OV <sub>DD</sub>	—
GPIO_PC22/UPC1_RxADDR[2]	C16	IO	OV <sub>DD</sub>	—
GPIO_PC23/UPC1_RxADDR[3]	D16	IO	OV <sub>DD</sub>	—
GPIO_PC24/UPC1_RxSOC/SER5_CD	A16	IO	OV <sub>DD</sub>	—
GPIO_PC25/UPC1_RxCLAV	D20	IO	OV <sub>DD</sub>	—
GPIO_PC26/UPC1_RxPRTY/CE_EXT_REQ2	E23	IO	OV <sub>DD</sub>	—
GPIO_PC27/UPC1_RxEN	B17	IO	OV <sub>DD</sub>	—
GPIO_PC28/UPC1_TxSOC	B22	IO	OV <sub>DD</sub>	—
GPIO_PC29/UPC1_TxCLAV/SER5_CTS	A17	IO	OV <sub>DD</sub>	—
GPIO_PC30/UPC1_TxPRTY	A22	IO	OV <sub>DD</sub>	—
GPIO_PC31/UPC1_TxEN/SER5_RTS	C20	IO	OV <sub>DD</sub>	—
GPIO_PD0/SPIMOSI	A2	IO	OV <sub>DD</sub>	—
GPIO_PD1/SPIMISO	B2	IO	OV <sub>DD</sub>	—
GPIO_PD2/SPICLK	B3	IO	OV <sub>DD</sub>	—
GPIO_PD3/SPISEL	A3	IO	OV <sub>DD</sub>	—
GPIO_PD4/SPI_MDIO/CE_MUX_MDIO	A4	IO	OV <sub>DD</sub>	—
GPIO_PD5/SPI_MDC/CE_MUX_MDC	B4	IO	OV <sub>DD</sub>	—
GPIO_PD6/CLK8/BRGO16/CE_EXT_REQ3	F24	IO	OV <sub>DD</sub>	—
GPIO_PD7/GTM1_TIN1/GTM2_TIN2/CLK5	G24	IO	OV <sub>DD</sub>	—
GPIO_PD8/GTM1_TGATE1/GTM2_TGATE2/CLK6	H24	IO	OV <sub>DD</sub>	—
GPIO_PD9/GTM1_TOUT1	D24	IO	OV <sub>DD</sub>	—

## Table 55. MPC8323E PBGA Pinout Listing (continued)



Package and Pin Listings

Signal	Package Pin Number	Pin Type	Power Supply	Notes
V <sub>DD</sub>	K10, K11, K12, K13, K14, K15, K16, K17, L10, L17, M10, M17, N10, N17, P10, P17, R10, R17, T10, T17, U10, U11, U12, U13, U14, U15, U16, U17	V <sub>DD</sub>	_	_
V <sub>SS</sub>	B23, E7, E11, E13, E17, E21, F11, F13, F17, F21, F23, G5, H22, K5, K6, L11, L12, L13, L14, L15, L16, L21, M11, M12, M13, M14, M15, M16, N6, N11, N12, N13, N14, N15, N16, P5, P11, P12, P13, P14, P15, P16, P21, R11, R12, R13, R14, R15, R16, R22, T6, T11, T12, T13, T14, T15, T16, U5, U21, V23, W5, W6, W21, W23, W24, Y22, AA5, AA6, AA22, AA25, AB7, AB13, AB19, AB22, AC10, AC12, AC16, AC20	V <sub>SS</sub>		
	No Connect			
NC	C22	_	—	—

#### Table 55. MPC8323E PBGA Pinout Listing (continued)

#### Notes:

1. This pin is an open drain signal. A weak pull-up resistor (1 k $\Omega$ ) should be placed on this pin to OV<sub>DD</sub>.

2. This pin is an open drain signal. A weak pull-up resistor (2–10 kΩ) should be placed on this pin to OV<sub>DD</sub>.

3. This output is actively driven during reset rather than being three-stated during reset.

4. These JTAG and local bus pins have weak internal pull-up P-FETs that are always enabled.

5. This pin should have a weak pull up if the chip is in PCI host mode. Follow the PCI specification's recommendation.

6. This pin must always be tied to GND. 7. This pin has weak internal pull-down N-FET that is always enabled.8. Though this pin has weak internal pull-up yet it is recommended to apply an external pull-up.



Characteristic <sup>1</sup>	Max Operating Frequency	Unit
DDR1/DDR2 memory bus frequency (MCLK) <sup>2</sup>	133	MHz
Local bus frequency (LCLKn) <sup>3</sup>	66	MHz
PCI input frequency (CLKIN or PCI_CLK)	66	MHz

#### Table 57. Operating Frequencies for PBGA (continued)

<sup>1</sup> The CLKIN frequency, RCWL[SPMF], and RCWL[COREPLL] settings must be chosen such that the resulting *csb\_clk*, MCLK, LCLK[0:2], and *core\_clk* frequencies do not exceed their respective maximum or minimum operating frequencies.

<sup>2</sup> The DDR1/DDR2 data rate is 2× the DDR1/DDR2 memory bus frequency.

<sup>3</sup> The local bus frequency is 1/2, 1/4, or 1/8 of the *lb\_clk* frequency (depending on LCRR[CLKDIV]) which is in turn 1× or 2× the *csb\_clk* frequency (depending on RCWL[LBCM]).

# 22.4 System PLL Configuration

The system PLL is controlled by the RCWL[SPMF] parameter. Table 58 shows the multiplication factor encodings for the system PLL.

## NOTE

System PLL VCO frequency =  $2 \times (CSB \text{ frequency}) \times (System PLL VCO divider})$ .

The VCO divider needs to be set properly so that the System PLL VCO frequency is in the range of 300–600 MHz.

RCWL[SPMF]	System PLL Multiplication Factor
0000	Reserved
0001	Reserved
0010	× 2
0011	× 3
0100	× 4
0101	× 5
0110	× 6
0111-1111	Reserved

## Table 58. System PLL Multiplication Factors

As described in Section 22, "Clocking," the LBCM, DDRCM, and SPMF parameters in the reset configuration word low and the CFG\_CLKIN\_DIV configuration input signal select the ratio between the primary clock input (CLKIN or PCI\_CLK) and the internal coherent system bus clock (*csb\_clk*). Table 59



Document Revision History

# 25.2 Part Marking

Parts are marked as in the example shown in Figure 46.



ATWLYYWW is the traceability code. CCCCC is the country code. MMMMM is the mask number. YWWLAZ is the assembly traceability code.

Figure 46. Freescale Part Marking for PBGA Devices

# 26 Document Revision History

Table 67 provides a revision history for this hardware specification.

## Table 67. Document Revision History

Rev. No.	Date	Substantive Change(s)
4	09/2010	<ul> <li>Replaced all instances of "LCCR" with "LCRR" throughout.</li> <li>Added footnotes 3 and 4 in Table 2, "Recommended Operating Conditions<sup>3</sup>."</li> <li>Modified Section 8.1.1, "DC Electrical Characteristics."</li> <li>Modified Table 23, "MII Transmit AC Timing Specifications."</li> <li>Modified Table 24, "MII Receive AC Timing Specifications."</li> <li>Added footnote 7 and 8, and modified some signal names in Table 55, "MPC8323E PBGA Pinout Listing."</li> </ul>
3	12/2009	<ul> <li>Removed references for note 4 from Table 1.</li> <li>Added Figure 2 in Section 2.1.2, "Power Supply Voltage Specification.</li> <li>Added symbol T<sub>A</sub> in Table 2.</li> <li>Added footnote 2 in Table 2.</li> <li>Added a note in Section 4, "Clock Input Timing for rise/fall time of QE input pins.</li> <li>Modified CLKIN, PCI_CLK rise/fall time parameters in Table 8. Modified min value of t<sub>MCK</sub> in Table 19.</li> <li>Modified Figure 43.</li> <li>Modified formula for ce_clk calculation in Section 22.3, "System Clock Domains.</li> <li>Added a note in Section 22.4, "System PLL Configuration.</li> <li>Removed the signal ECID_TMODE_IN from Table 55.</li> <li>Removed all references of RST signals from Table 55.</li> </ul>